

SI3900DV-T1-GE3 Information


For Reference Only

Part Number [SI3900DV-T1-GE3](#)
Manufacturer Vishay Siliconix
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Arrays](#)
Description MOSFET 2N-CH 20V 2A 6-TSOP
Package SOT-23-6 Thin, TSOT-23-6
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


SI3900DV-T1-GE3 Specifications

Manufacturer Part Number	SI3900DV-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays
Package	SOT-23-6 Thin, TSOT-23-6
Series	TrenchFET?
FET Type	2 N-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	2A
Rds On (Max) @ Id, Vgs	125 mOhm @ 2.4A, 4.5V
Vgs(th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	4nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	-
Power - Max	830mW
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	SOT-23-6 Thin, TSOT-23-6
Supplier Device Package	6-TSOP

[Report errors?](#)

SI3900DV-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SI3900DV-T1-GE3 Payment Methods



SI3900DV-T1-GE3 Shipping Methods



If you have any question about SI3900DV-T1-GE3, please do not hesitate to contact us!

Website: <https://www.heisener.com>

E-mail: salesdept@heisener.com